



COJC
PATENT

Attorney Docket No.: SAM-0554

Customer No.: 29344

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Seung-hwan Lee, *et al.*
Serial No.: 10/823,420
Filing Date: April 13, 2004
Patent Number: 7,033,895
Issue Date: April 25, 2006
Examiner: Huynh, Andy
Group Art Unit: 2818
Title: METHOD OF FABRICATING A MOS TRANSISTOR WITH
ELEVATED SOURCE/DRAIN STRUCTURE USING A SELECTIVE
EPITAXIAL GROWTH PROCESS (As Amended)

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

I hereby certify that this correspondence is being deposited with the United States Post Office as First Class Mail on the date indicated below in an envelope addressed to Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

6/19/06
Date

Seth Pitman
Seth Pitman

Certificate of Corrections Branch
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

TRANSMITTAL LETTER

Sir:

Certificate
JUN 26 2006
of Correction

Enclosed herewith for filing in the above-identified patent application please find the following:

1. Petition for Certificate of Correction under 37 C.F.R. § 1.322;
2. Certificate of Correction; and
3. Return Postcard

In connection with the foregoing matter, please charge any additional fees which may be due, or credit any overpayment, to Deposit Account Number 50-1798. A duplicate copy of this letter is provided for this purpose.

Respectfully submitted,

Date: June 19, 2006
Mills & Onello, LLP
Eleven Beacon Street, Suite 605
Boston, MA 02108
Telephone: (617) 994-4900
Facsimile: (617) 742-7774
J:\SAM\0554\CofC\transcertcor.wpd

Anthony P. Onello, Jr.
Anthony P. Onello, Jr.
Registration Number 38,572
Attorney for Applicants

JUN 26 2006



PATENT
Attorney Docket No.: SAM-0554
Customer No.: 29344

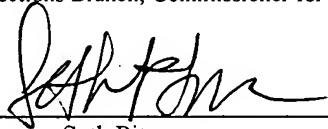
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Seung-hwan Lee, *et al.*
Serial No.: 10/823,420
Filing Date: April 13, 2004
Patent Number: 7,033,895
Issue Date: April 25, 2006
Examiner: Huynh, Andy
Group Art Unit: 2818
Title: METHOD OF FABRICATING A MOS TRANSISTOR WITH
ELEVATED SOURCE/DRAIN STRUCTURE USING A SELECTIVE
EPITAXIAL GROWTH PROCESS (As Amended)

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

I hereby certify that this correspondence is being deposited with the United States Post Office as First Class Mail on the date indicated below in an envelope addressed to Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

6/19/06
Date


Seth Pitman

Certificate of Corrections Branch
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

TRANSMITTAL LETTER

Sir:


Enclosed herewith for filing in the above-identified patent application please find the following:

1. Petition for Certificate of Correction under 37 C.F.R. § 1.322;
2. Certificate of Correction; and
3. Return Postcard

In connection with the foregoing matter, please charge any additional fees which may be due, or credit any overpayment, to Deposit Account Number 50-1798. A duplicate copy of this letter is provided for this purpose.

Respectfully submitted,

Date: June 19, 2006
Mills & Onello, LLP
Eleven Beacon Street, Suite 605
Boston, MA 02108
Telephone: (617) 994-4900
Facsimile: (617) 742-7774
J:\SAM\0554\CofC\transcertcor.wpd


Anthony P. Onello, Jr.
Registration Number 38,572
Attorney for Applicants

JUN 26 2006



PATENT
Attorney Docket No.: SAM-0554

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Seung-hwan Lee, *et al.*
Serial No.: 10/823,420
Filing Date: April 13, 2004
Patent Number: 7,033,895
Issue Date: April 25, 2006
Examiner: Huynh, Andy
Group Art Unit: 2818
Title: METHOD OF FABRICATING A MOS TRANSISTOR WITH
ELEVATED SOURCE/DRAIN STRUCTURE USING A SELECTIVE
EPITAXIAL GROWTH PROCESS (As Amended)

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

I hereby certify that this correspondence is being deposited with the United States Post Office as First Class Mail on the date indicated below in an envelope addressed to Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

06/19/06
Date


Seth Pitman

Certificate of Corrections Branch
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

PETITION FOR CERTIFICATE OF CORRECTION UNDER 37 C.F.R. § 1.322

Sir:

The patentee of the above-identified patent, through its attorney, hereby petitions for issuance of a Certificate of Correction in the above-identified patent. A certificate is required to correct the errors in the claims as follows:

At Column 6, Claim 1, Line 23, delete "epi-laver" and insert --epi-layer--.

At Column 7, Claim 14, Line 16, delete "." after "C".

JUN 23 2006

Applicant(s): Seung-hwan Lee, *et al.*
Serial No.: 10/823,420

At Column 8, Claim 21, Line 13, delete "10" and insert --10⁻⁵--.

At Column 8, Claim 22, Line 17, delete "." after "C".

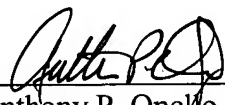
It is respectfully requested that a Certificate of Correction be issued to correct the errors in the claims.

The correction is not believed to involve such change as would constitute new matter or require examination. Since the error is the fault of the United States Patent and Trademark Office, it is believed that no fee is due.

Respectfully submitted,

Date: June 19, 2006
Mills & Onello, LLP
Eleven Beacon Street, Suite 605
Boston, MA 02108
Telephone: (617) 994-4900
Facsimile: (617) 742-7774

J:\SAM\0554\CofC\petitcertcorr.wpd


Anthony P. Onello, Jr.
Registration Number 38,572
Attorney for Applicant

UNITED STATES PATENT AND TRADEMARK OFFICE

CERTIFICATE OF CORRECTION

PATENT NO.: 7,033,895 B2
DATED: April 25, 2006
INVENTOR(S): Seung-hwan Lee
Moon-han Park
Hwa-sung Rhee
Ho Lee
Jae-yoon Yoo

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

At Column 6, Claim 1, Line 23, delete "epi-laver" and insert --epi-layer--.

At Column 7, Claim 14, Line 16, delete "." after "C".

At Column 8, Claim 21, Line 13, delete "10 " and insert --10⁵--.

At Column 8, Claim 22, Line 17, delete "." after "C".

MAILING ADDRESS OF SENDER:

Anthony P. Onello, Jr.
Mills & Onello LLP
Eleven Beacon Street, Suite 605
Boston, MA 02108

J:\SAM\0554\CoFC\certificcorrect.wpd

PATENT NO. 7,033,895 B2

APR 26 2006